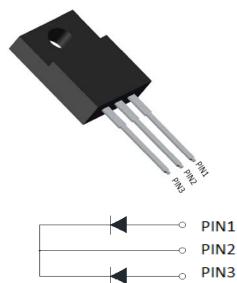




# **Schottky Diodes**



### **Features**

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

### **Typical Applications**

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

### **Mechanical Data**

• Package: ITO-220AB

Molding compound meets UL 94 V-0 flammability

rating, RoHS-compliant

• Terminals: Tin plated leads, solderable per J-STD-

002 and JESD22-B102 • Polarity: As marked

## ■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR3045FCT
Device marking code			MBR3045FCT
Repetitive Peak Reverse Voltage	VRRM	V	45
Average Rectified Output Current @60Hz sine wave, R-load, Ta=25℃	lo	А	30
Surge(Non-repetitive)Forward Current @60Hz half sine-wave,1 cycle, Ta=25°C	IFSM	А	250
Current Squared Time @1ms≤t<8.3ms Tj=25℃,	l <sup>2</sup> t	A <sup>2</sup> s	262
Storage Temperature	T <sub>Stg</sub>	$^{\circ}$	-55 ~ <b>+</b> 150
Junction Temperature	Tj	°C	-55 ~ +150

## **■Electrical Characteristics** (T<sub>a</sub>=25°C Unless otherwise specified)

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PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR3045FCT
Maximum instantaneous forward voltage drop per diode	VFM	٧	IFM=15.0A	0.6
Maximum DC reverse current at rated DC blocking voltage per diode	IRRM1	mA	VRM=VRRM T <sub>a</sub> =25℃	0.2
	IRRM2		VRM=VRRM Ta=100℃	100

### **■Thermal Characteristics** (T<sub>a</sub>=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MBR3045FCT
Thermal Resistance	Between junction and case	R <sub>0</sub> J-C	°C <b>/W</b>	4.0



# MBR3045FCT

**■Ordering Information** (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR3045FCT	Approximate 1.6	50	1000	5000	Tube

## **■Characteristics** (Typical)

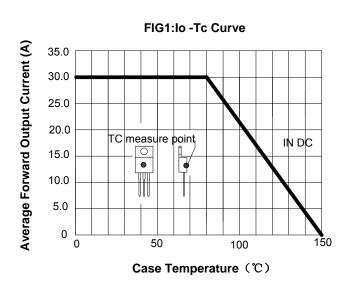
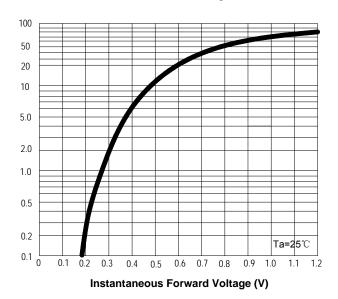
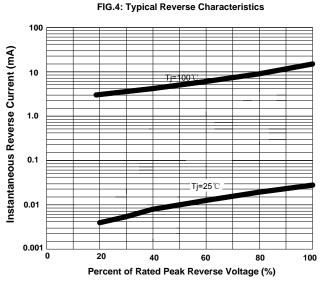


FIG2:Surge Forward Current Capability 300 Peak Forward Surge Current (A) 250 200 8.3ms Single Half Sine-Wave 150 JEDEC Method 100 0 2 20 50 10 100 **Number of Cycles** 

FIG3: Forward Voltage

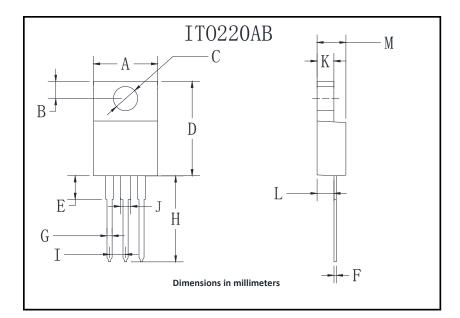






# MBR3045FCT

## **■**Outline Dimensions



ITO-220AB				
Dim	Min	Max		
Α	9.7	10.7		
В	2.15	3.25		
С	2.6	3.8		
D	14.4	15.9		
Е	3.1	4.5		
F	0.4	0.8		
G	0.4	0.8		
Н	12.7	14.2		
I	1.80	2.95		
J	1.4	1.8		
K	2.1	3.56		
L	2.1	3.2		
М	3.9	5.1		



# MBR3045FCT

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